

Features

- High breakdown voltage
- Low turn-on voltage
- Guard ring construction for transient protection



SOD-123



Schematic Diagram

Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	40	V
Maximum RMS Voltage	V _{RMS}	28	V
Maximum DC Blocking Voltage	V _{DC}	40	V
Maximum Average Forward Rectified Current	I _{FM}	1.0	A
Peak Forward Surge Current 8.3ms Single Half Sine-wave	I _{FSM}	30	A
Power Dissipation	P _D	500	mW
Thermal Resistance Junction to Ambient Air	R _{θJA}	250	°C/W
Junction Temperature Range	T _J	+125	°C
Storage Temperature Range	T _{STG}	-50 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Value	Unit
Maximum Reverse Breakdown Voltage	V _R	I _R =1mA	40	V
Maximum Reverse Current	I _R	V _R =40V	1.0	mA
Maximum Forward Voltage	V _F	I _F =1.0A	0.45	V
Typical Junction Capacitance	C _J	V _R =4.0V, f=1MHz	120	pF

Typical Electrical and Thermal Characteristic Curves

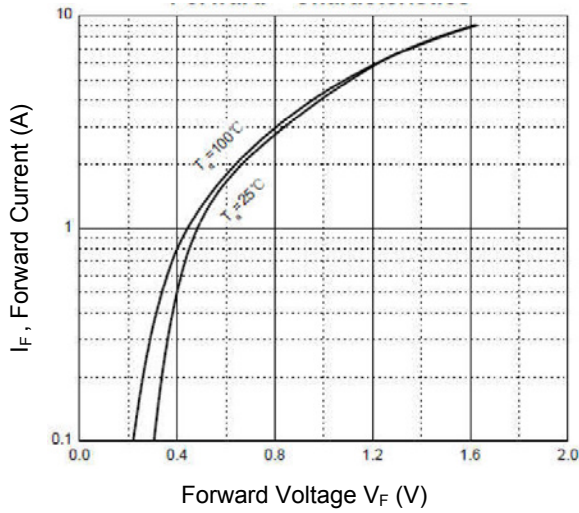


Figure 1. Forward Characteristics

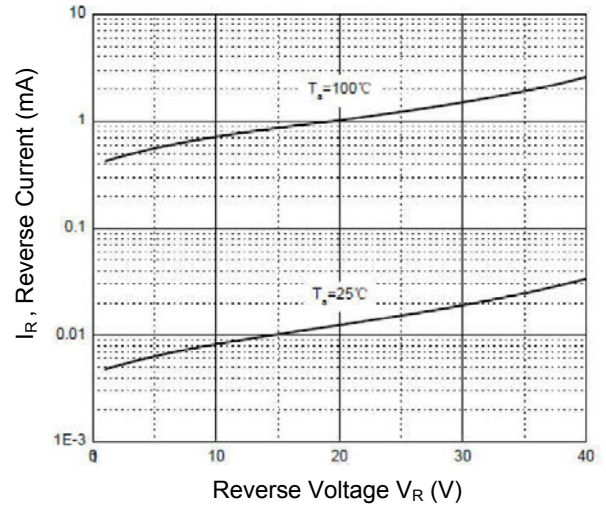


Figure 2. Reverse Characteristics

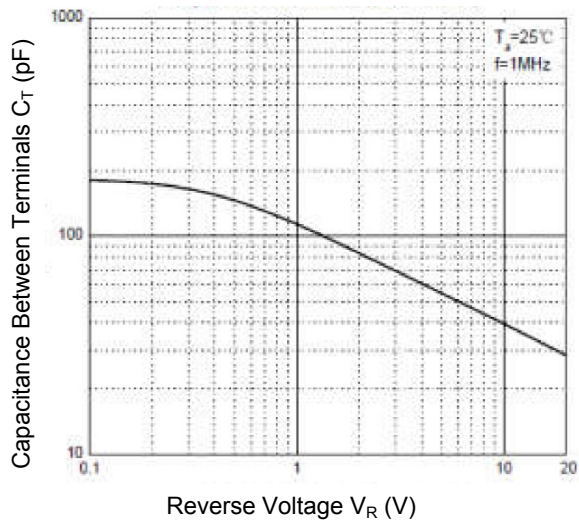


Figure 3. Capacitance Characteristics

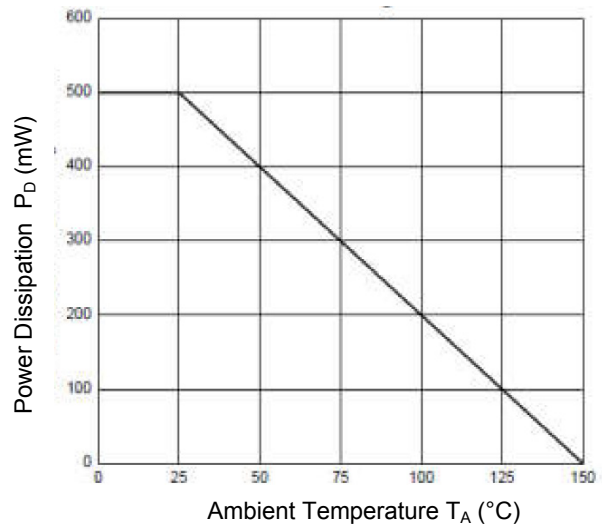
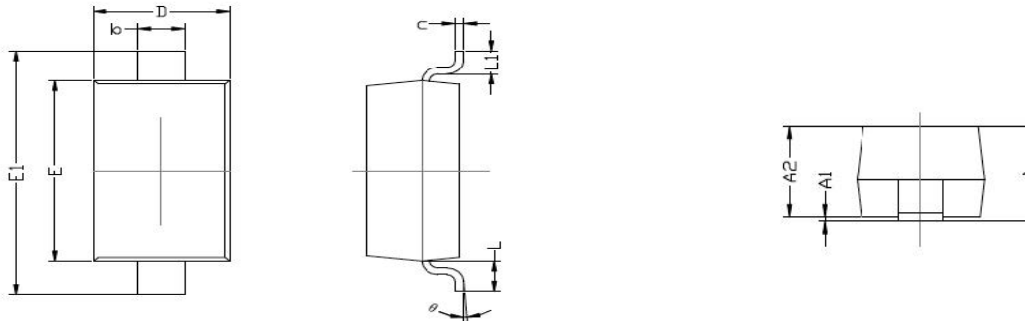


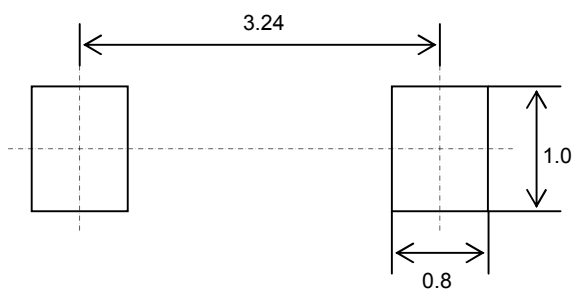
Figure 4. Power Derating Curve

Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.450	0.650	0.018	0.026
c	0.080	0.150	0.003	0.006
D	1.500	1.700	0.059	0.067
E	2.600	2.800	0.102	0.110
E1	3.550	3.850	0.140	0.152
L	0.500 REF		0.020 REF	
L1	0.250	0.450	0.010	0.018
θ	0°	8°	0°	8°

Recommended Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

Order Information

Device	Package	Carrier	Quantity	Marking
GSB5819WL	SOD-123	Tape & Reel	3,000pcs / Reel	C19